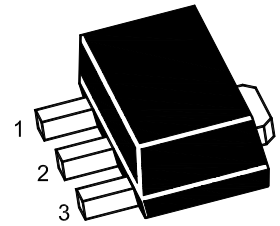


Features

- Low saturation voltage

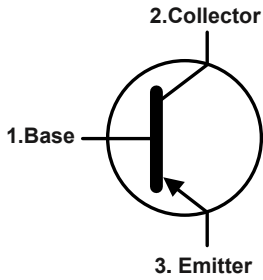
SOT-89



1.Base 2.Collector 3. Emitter

Marking Code : S46

Equivalent Circuit



Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	50	V
Collector Emitter Voltage	$-V_{CEO}$	50	V
Emitter Base Voltage	$-V_{EBO}$	5	V
Collector Current	$-I_C$	3	A
Pulsed Collector Current	$-I_{CM}$	5	A
Base Current	$-I_B$	0.5	A
Maximum Power Dissipation ^{Note1}	P_D	550	mW
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-65 to +150	°C

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resisitance Junction to Ambient ^{Note1}	$R_{\theta JA}$	225	°C/W

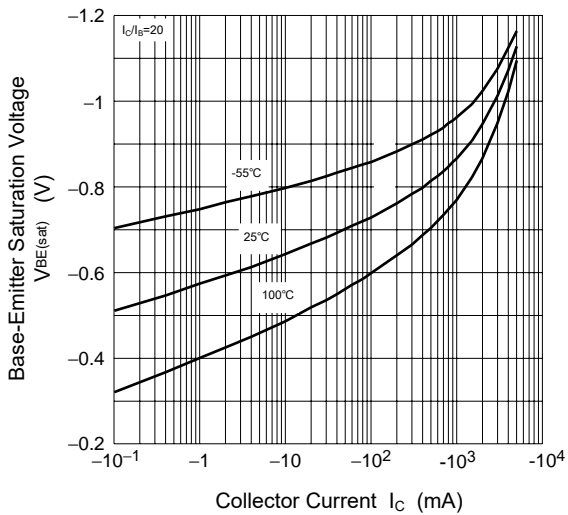
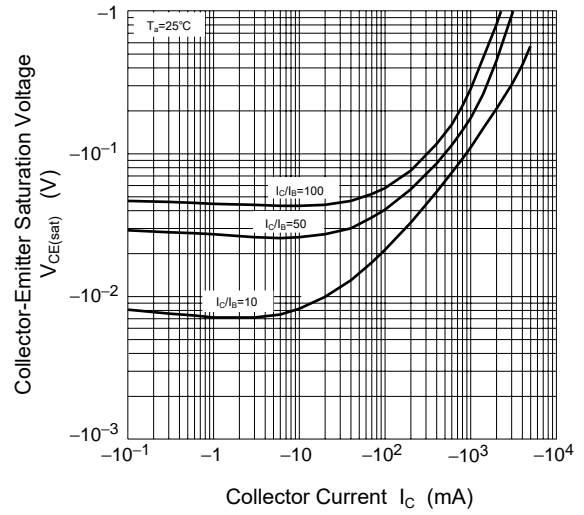
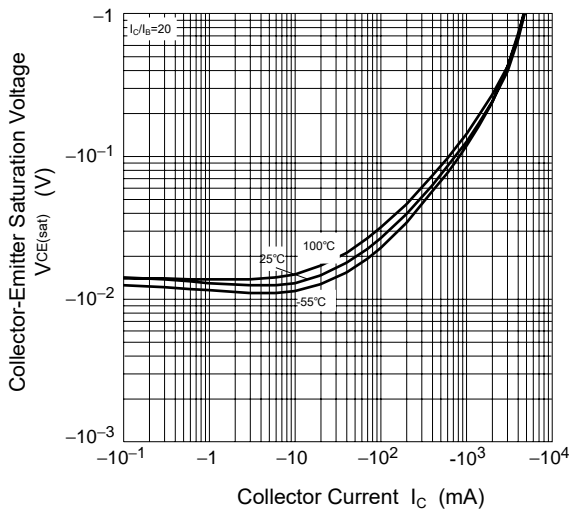
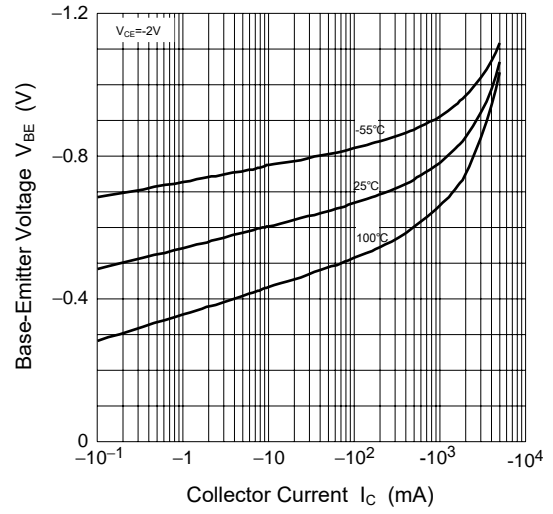
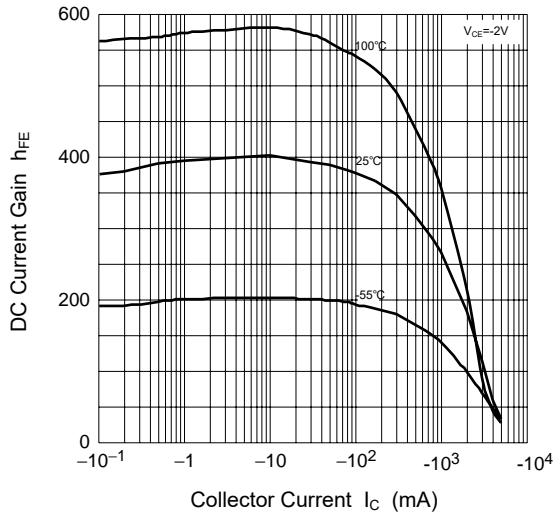
Note: 1.Device mounted on a FR4 printed-circuit board; single-sided copper; tin-plated; standard footprint.



Electrical Characteristics (T_A=25°C)

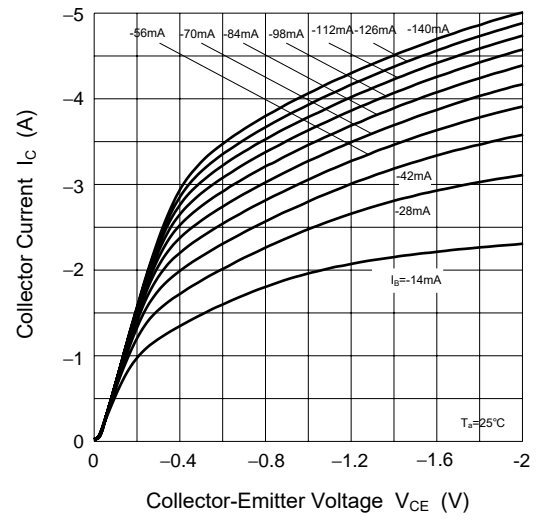
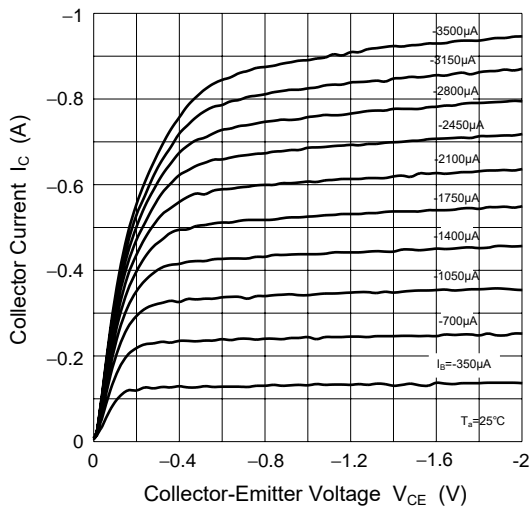
Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at V _{CE} = -2 V, I _C = -0.1 A at V _{CE} = -2 V, I _C = -0.5 A at V _{CE} = -2 V, I _C = -1 A at V _{CE} = -2 V, I _C = -2 A at V _{CE} = -2 V, I _C = -3 A	H _{FE}	200 200 200 130 80	-- -- 450 -- --	--
Collector Base Cutoff Current at V _{CB} = -50 V	-I _{CBO}	--	100	nA
Collector Emitter Cutoff Current at V _{CE} = -50 V	-I _{CES}	--	100	nA
Emitter Base Cutoff Current at V _{EB} = -5 V	-I _{EBO}	--	100	nA
Collector Emitter Saturation Voltage at I _C = -500 mA, I _B = -50 mA at I _C = -2 A, I _B = -100 mA at I _C = -2 A, I _B = -200 mA at I _C = -3 A, I _B = -300 mA	-V _{CE(sat)}	-- -- -- --	90 320 270 390	mV
Base Emitter Saturation Voltage at I _C = -2 A, I _B = -100 mA at I _C = -3 A, I _B = -300 mA	-V _{BE(sat)}	-- --	1.1 1.2	V
Base Emitter On Voltage at V _{CE} = -2 V, I _C = -1 A	-V _{BE(on)}	--	1.1	V
Transition Frequency at V _{CE} = -5 V, I _C = -100 mA, f = 100 MHz	F _T	100	--	MHz
Output Capacitance at V _{CB} = -10 V, I _E = 0, f = 1 MHz	C _{ob}	--	35	pF

Typical Characteristic Curves





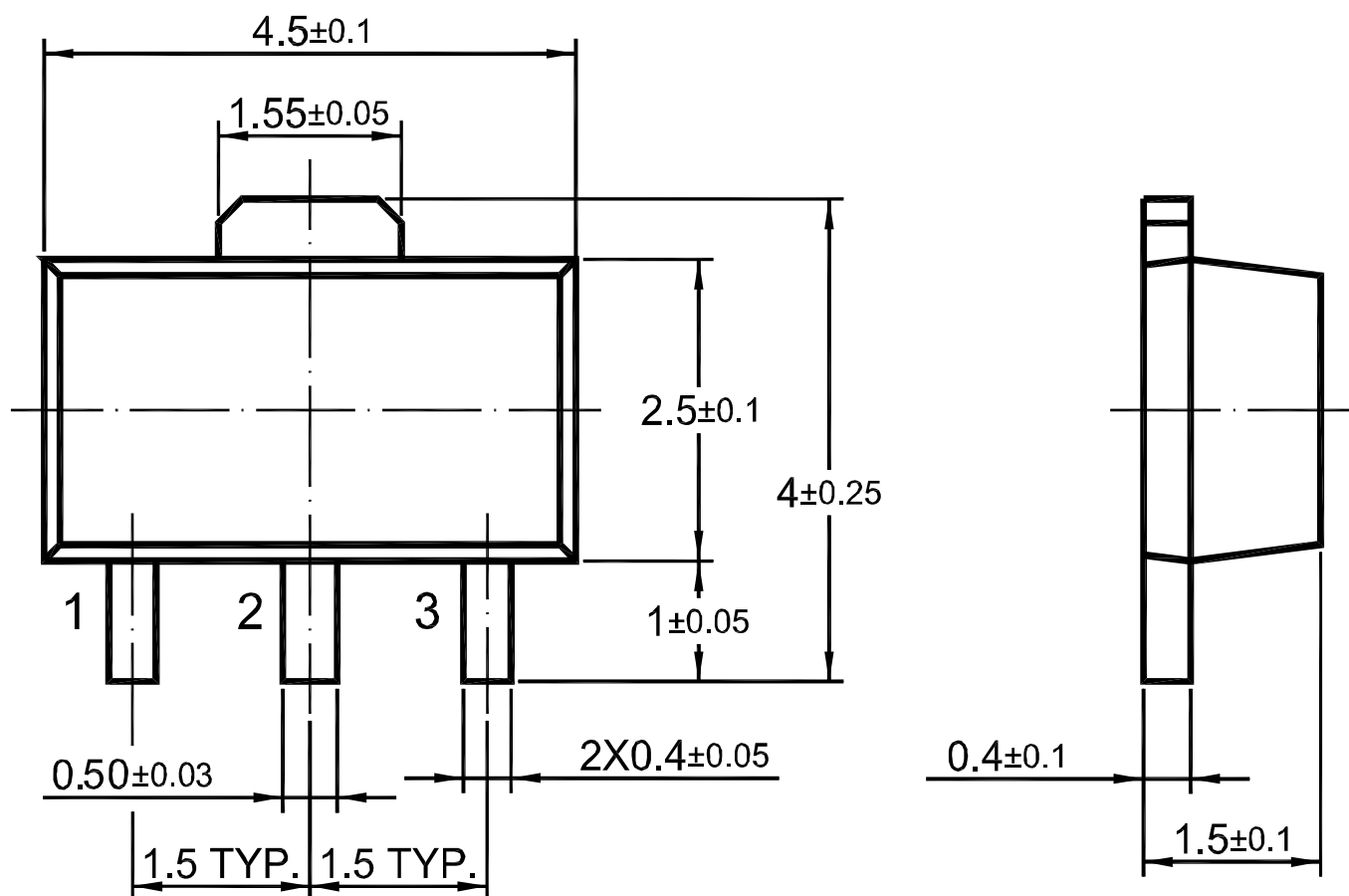
PBSS5350SQ PNP Transistor



Package Outline

SOT-89

Dimensions in mm

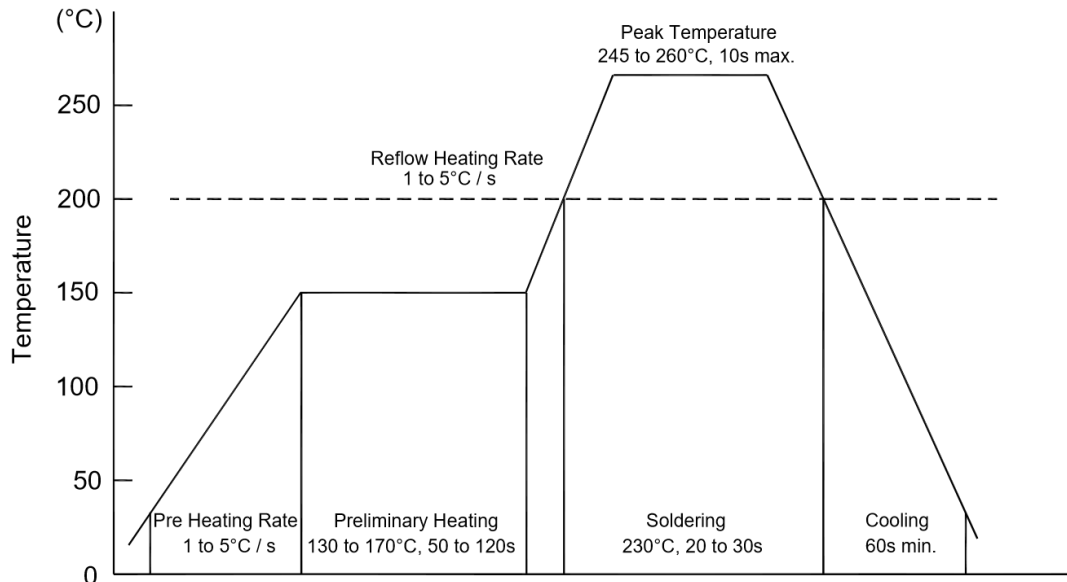


Ordering Information

Device	Package	Shipping
PBSS5350SQ	SOT-89	1,000PCS/Reel&7inches
		3,000PCS/Reel&13inches

Conditions of Soldering and Storage

◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

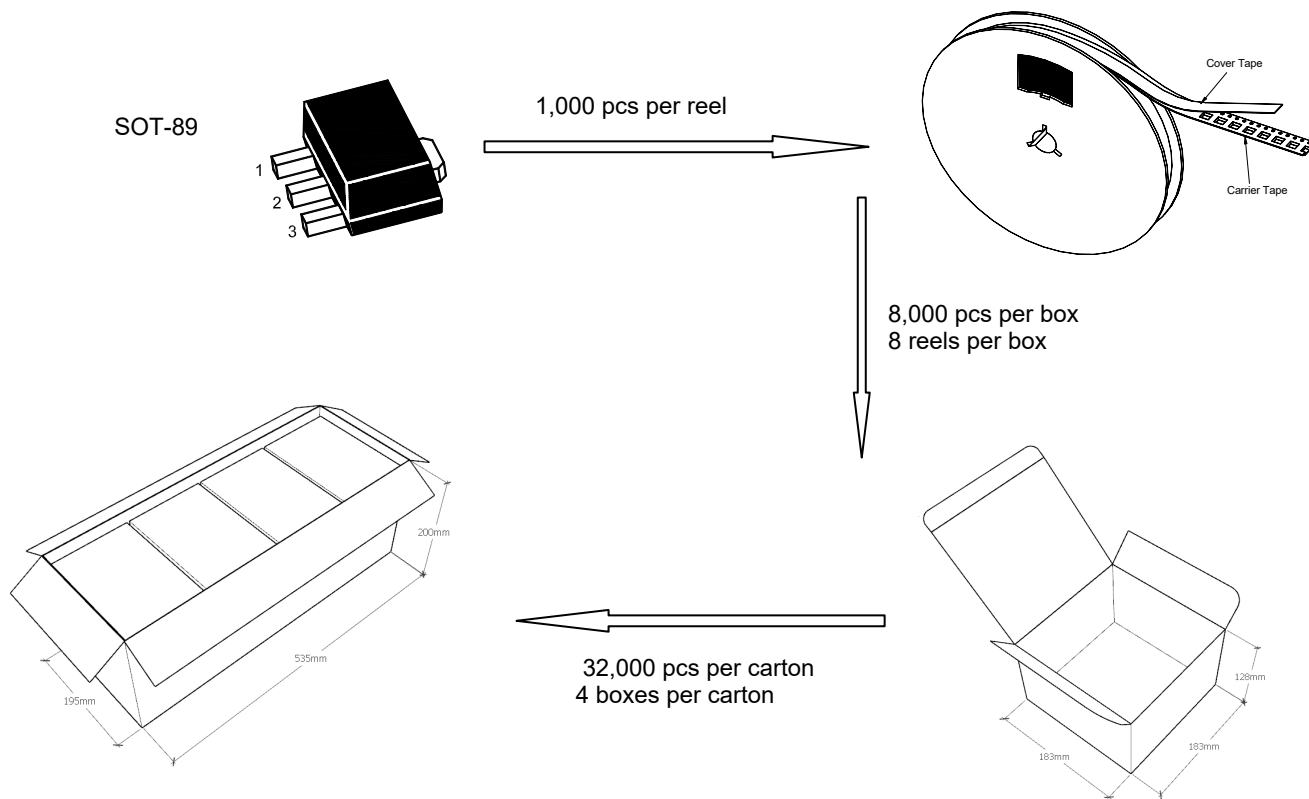
- Temperature: 370 °C
- Time: 3s max.
- Times: one time

◆ Storage conditions

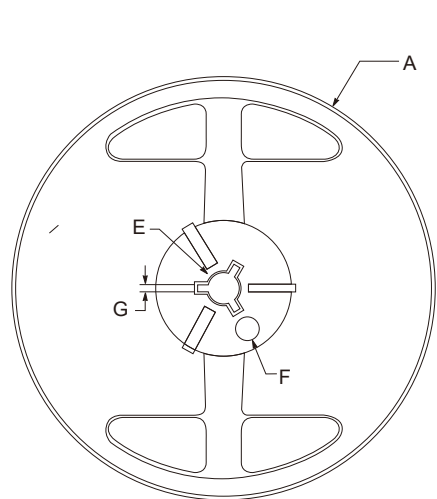
- **Temperature**
5 to 40 °C
- **Humidity**
30 to 80% RH
- **Recommended period**
One year after manufacturing

Package Specifications

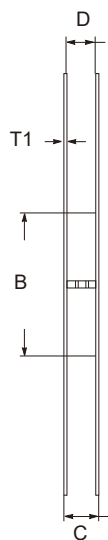
- The method of packaging (1,000PCS/Reel&7inches)



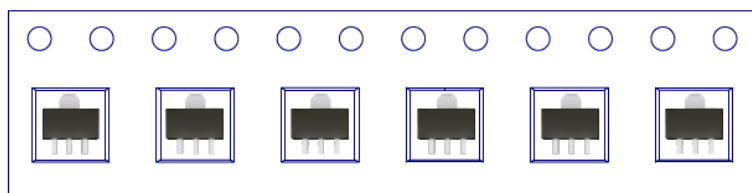
◆ Embossed tape and reel data



Reel (7")

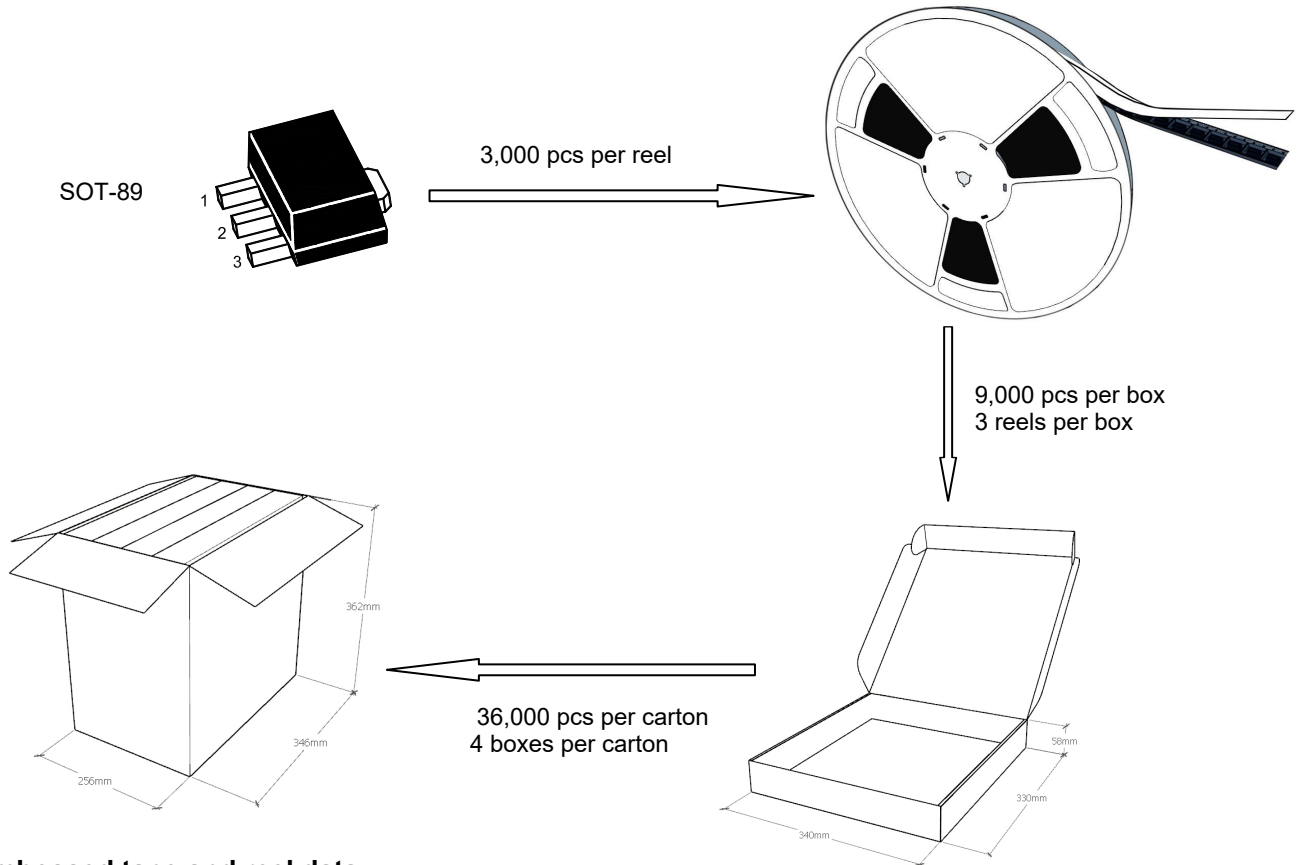


symbol	Value(unit:mm)
A	$\Phi 179 \pm 1$
B	60.5 ± 0.2
C	15.3 ± 0.3
D	12.5~13.7
E	$\Phi 13.5 \pm 0.2$
F	$\Phi 10.0 \pm 0.2$
G	2.7 ± 0.2
T1	1.0 ± 0.2

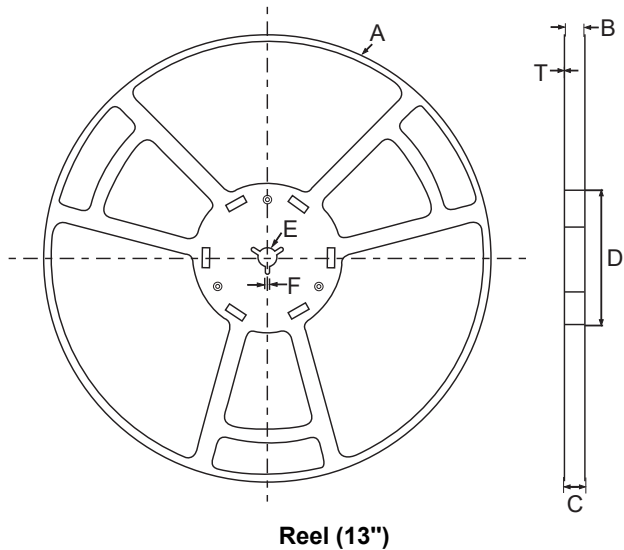


Package Specifications

- The method of packaging (3,000PCS/Reel&13inches)



◆ Embossed tape and reel data



symbol	Value(unit:mm)
A	$\Phi 330 \pm 1$
B	12.7 ± 0.5
C	16.5 ± 0.3
D	$\Phi 99.5 \pm 0.5$
E	$\Phi 13.6 \pm 0.3$
F	2.8 ± 0.3
T1	1.9 ± 0.2

